# **ON Semiconductor**

# Is Now



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# **D-Type Flip-Flop with Asynchronous Clear**

# **NL17SZ175**

The NL17SZ175 is a single, positive edge triggered, D-type CMOS Flip-Flop with Asynchronous Clear operating from a 1.65 V to 5.5 V supply.

#### **Features**

- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- 2.6 ns  $t_{PD}$  at  $V_{CC} = 5 \text{ V (Typ)}$
- Inputs/Outputs Overvoltage Tolerant up to 5.5 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Sink 32 mA at 4.5 V
- Available in SC-88, SC-74 and UDFN6 Packages
- Chip Complexity < 100 FETs
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

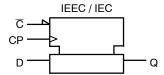
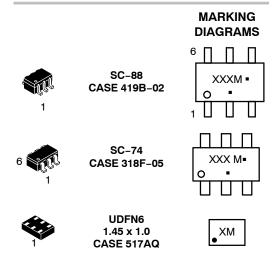


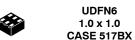
Figure 1. Logic Symbol



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1



X, XXX = Specific Device Code
M = Date Code\*
W = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

# **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 7 of this data sheet.

# **Connection Diagrams**

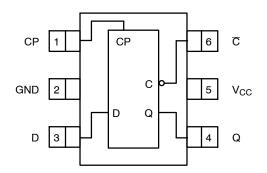


Figure 2. SC-88/SC-74 (Top View)

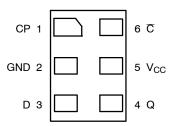


Figure 3. UDFN6(Top Through View)

# **PIN DESCRIPTIONS**

Pin Name	Description
D	Data Input
СР	Clock Pulse Input
C	Clear Input
Q	Flip-Flop Output

# **FUNCTION TABLE**

	Output		
СР	D	C	Q
\	L	Н	L
\	Н	Н	Н
/	Х	Н	Qn
Х	Х	L	L

H = HIGH Logic Level L = LOW Logic Level

Qn = No Change in Data X = Immaterial

# **MAXIMUM RATINGS**

Symbol	Characteristic	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +6.5 -0.5 to +6.5	٧
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	<b>-50</b>	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-50	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground P	in	±100	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
$T_L$	Lead Temperature, 1 mm from Case for 10 sec	s	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	SC-88 SC-74 UDFN6	377 320 154	°C/W
$P_{D}$	Power Dissipation in Still Air	SC-88 SC-74 UDFN6	332 390 812	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Applicable to devices with outputs that may be tri-stated.
- Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
   HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
- 4. Tested to EIA/JESD78 Class II.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Cha	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage		1.65	5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	
T <sub>A</sub>	Operating Temperature Range		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0 0 0	20 20 10 5	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# DC ELECTRICAL CHARACTERISTICS

	V <sub>CC</sub>		T,	( = 25°C		-55°C ≤ T	<sub>A</sub> ≤ 125°C		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
V <sub>IH</sub>	High-Level Input		1.65 to 1.95	0.65 V <sub>CC</sub>	-	_	0.65 V <sub>CC</sub>	_	V
	Voltage		2.3 to 5.5	0.70 V <sub>CC</sub>	-	-	0.70 V <sub>CC</sub>	-	
$V_{IL}$	Low-Level Input		1.65 to 1.95	-	-	0.35 V <sub>CC</sub>	-	0.35 V <sub>CC</sub>	V
	Voltage		2.3 to 5.5	-	-	0.30 V <sub>CC</sub>	-	0.30 V <sub>CC</sub>	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{split} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OH} = -100  \mu\text{A} \\ &I_{OH} = -4 \text{ mA} \\ &I_{OH} = -8 \text{ mA} \\ &I_{OH} = -16 \text{ mA} \\ &I_{OH} = -24 \text{ mA} \\ &I_{OH} = -32 \text{ mA} \end{split}$	1.65 to 5.5 1.65 2.3 3 3 4.5	V <sub>CC</sub> - 0.1 1.29 1.9 2.4 2.3 3.8	V <sub>CC</sub> 1.52 2.1 2.7 2.5 4	- - - - -	V <sub>CC</sub> - 0.1 1.29 1.9 2.4 2.3 3.8	- - - -	V
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = 100  \mu\text{A} \\ I_{OH} = 4  m\text{A} \\ I_{OH} = 8  m\text{A} \\ I_{OH} = 16  m\text{A} \\ I_{OH} = 24  m\text{A} \\ I_{OH} = 32  m\text{A} \end{array}$	1.65 to 5.5 1.65 2.3 3 3 4.5	- - - -	- 0.08 0.12 0.24 0.26 0.31	0.1 0.24 0.3 0.4 0.55 0.55		0.1 0.24 0.3 0.4 0.55 0.55	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	1.65 to 5.5	-	-	±0.1	ı	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	ı	1.0	-	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5	-	=	1.0	-	10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

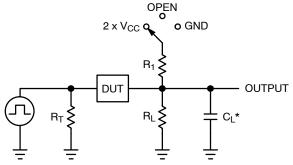
# **AC ELECTRICAL CHARACTERISTICS**

					T <sub>A</sub> = +25°C	;	$T_A = -40$	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
$f_{MAX}$	Maximum Clock Frequency	1.65	C <sub>L</sub> = 50 pF,	-	-	-	100	-	MHz
	(Figure 4, 5)	1.8	$R_L = 500 \Omega$	-	-	_	100	-	
		2.3 to 2.7	1	-	-	-	125	-	
		3.0 to 3.6		-	-	-	150	-	
		4.5 to 5.5		-	-	-	175	-	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay, CP to Q	1.65	C <sub>L</sub> = 15 pF,	-	9.8	15.0	-	16.5	ns
	(Figure 4, 5)	1.8	$R_L = 1 M\Omega$	-	6.5	10.0	-	11.0	
		2.3 to 2.7	1	-	3.8	6.5	-	7.0	
		3.0 to 3.6	1	-	2.8	4.5	-	5.0	
		4.5 to 5.5	1	-	2.2	3.5	-	3.8	
		3.0 to 3.6	$C_L = 50 \text{ pF},$	-	3.4	5.5	-	6.2	
		4.5 to 5.5	$R_L = 500 \Omega$	-	2.6	4.0	-	4.7	
t <sub>PHL</sub>	Propagation Delay, C to Q	1.65	C <sub>L</sub> = 15 pF,	-	9.8	13.5	-	15.0	ns
	(Figure 4, 5)	1.8	$R_L = 1 M\Omega$	-	6.5	9.0	-	10.0	- - -
		2.3 to 2.7		_	3.8	6.0	_	6.4	
		3.0 to 3.6		-	2.8	4.3	-	4.6	
		4.5 to 5.5		-	2.2	3.2	-	3.5	
		3.0 to 3.6	C <sub>L</sub> = 50 pF,	-	3.4	5.3	-	5.8	
		4.5 to 5.5	$R_L = 500 \Omega$	-	2.7	4.0	-	4.5	
t <sub>S</sub>	Setup Time, CP to D	2.3 to 2.7	C <sub>L</sub> = 50 pF,	-	-	_	2.5	-	ns
	(Figure 4, 5)	3.0 to 3.6	$R_L = 500 \Omega$	_	-	_	2.0	-	
		4.5 to 5.5	1	-	-	-	1.5	-	
t <sub>H</sub>	Hold Time, CP to D	2.3 to 2.7	C <sub>L</sub> = 50 pF,	-	-	-	1.5	-	ns
	(Figure 4, 5)	3.0 to 3.6	$R_L = 500 \Omega$	-	-	-	1.5	-	
		4.5 to 5.5	1	-	-	-	1.5	-	
t <sub>W</sub>	Pulse Width, CP	2.3 to 2.7	$C_L = 50 \text{ pF},$	-	-	-	3.0	-	ns
	(Figure 4, 5)	3.0 to 3.6	$R_L = 500 \Omega$	-	-	-	2.8	-	
		4.5 to 5.5		-	-	-	2.5	-	
	Pulse Width, C	2.3 to 2.7	Clock HIGH	-	-	-	3.0	-	ns
	(Figure 4, 5)	3.0 to 3.6	or LOW $C_L = 50 \text{ pF},$	-	-	-	2.8	-	1
		4.5 to 5.5	$R_L = 500  \Omega$	-	-	-	2.5	-	
t <sub>rec</sub>	Recovery Time, C to CP	2.3 to 2.7	C <sub>L</sub> = 50 pF,	-	-	-	1.0	-	ns
	(Figure 4, 5)	3.0 to 3.6	$R_L = 500 \Omega$	-	-	-	1.0	-	1
		4.5 to 5.5	1	_	_	_	1.0	-	

# **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC}$ = 5.5 V, $V_{IN}$ = 0 V or $V_{CC}$	2.5	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$	4.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	10 MHz, $V_{CC}$ = 5.5 V, $V_{IN}$ = 0 V or $V_{CC}$	4.0	pF

C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle. C<sub>PD</sub> is related to I<sub>CCD</sub> dynamic operating current by the expression:
 I<sub>CCD</sub> = (C<sub>PD</sub>) (V<sub>CC</sub>) (f<sub>IN</sub>) + (I<sub>CC</sub>static).



 Position
 See AC Characteristics Table

 t<sub>PLH</sub> / t<sub>PHL</sub>
 Open
 See AC Characteristics Table

 t<sub>PLZ</sub> / t<sub>PZL</sub>
 2 x V<sub>CC</sub>
 50
 500
 500

 t<sub>PHZ</sub> / t<sub>PZH</sub>
 GND
 50
 500
 500

 $C_L, pF$ 

Switch

 $R_L, \Omega$ 

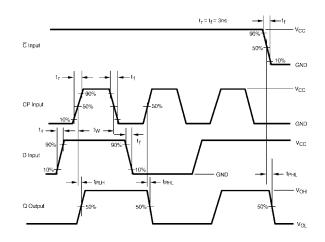
 $R_1,\,\Omega$ 

X = Don't Care

Test

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$  f = 1 MHz

Figure 4. Test Circuit



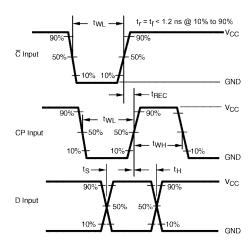


Figure 5. Switching Waveforms

		V <sub>n</sub>		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	$t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}$	V <sub>Y</sub> , V
1.65 to 1.95	V <sub>CC</sub> /2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	0.15
2.3 to 2.7	V <sub>CC</sub> /2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	0.15
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> / 2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	0.3

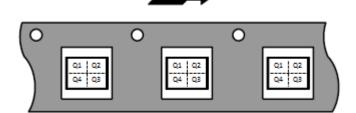
# **DEVICE ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
NL17SZ175DFT2G (In Development)	SC-88	TBD	Q4	3000 / Tape & Reel
NL17SZ175DBVT1G	SC-74	AT	Q4	3000 / Tape & Reel
NL17SZ175MU1TCG (In Development)	UDFN6, 1.45 x 1.0, 0.5P	TBD	Q4	3000 / Tape & Reel
NL17SZ175MU3TCG (In Development)	UDFN6, 1.0 x 1.0, 0.35P	TBD	Q4	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# Pin 1 Orientation in Tape and Reel

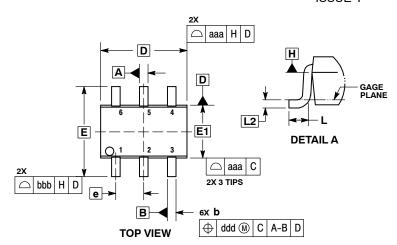
# Direction of Feed

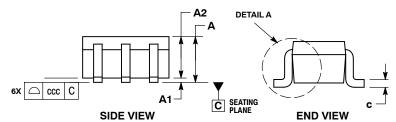


#### PACKAGE DIMENSIONS

# SC-88/SC70-6/SOT-363

CASE 419B-02 **ISSUE Y** 





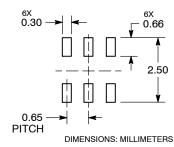
- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
  4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
  5. DATUMS A AND B ARE DETERMINED AT DATUM H.
  6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
  7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION

- DIMENSION 5 DOES NOT INCLUDE DAMBAR PROTRUSION.
  ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN
  EXCESS OF DIMENSION 5 AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER

	MIL	LIMETE	RS		INCHES	3
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10			0.043
A1	0.00		0.10	0.000		0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
е		0.65 BS	С	0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2		0.15 BS	C		0.006 BS	SC
aaa	0.15				0.006	
bbb	0.30				0.012	
ccc	0.10				0.004	
ddd		0.10			0.004	

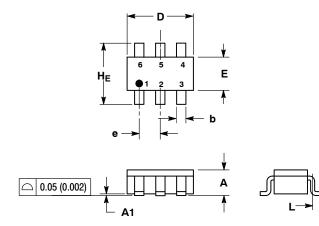
#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**

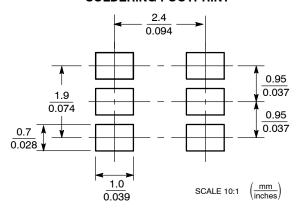
SC-74 CASE 318F-05 **ISSUE N** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM
  THICKNESS OF BASE MATERIAL.
  4. 318F-01, -02, -03, -04 OBSOLETE. NEW STANDARD 318F-05.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
С	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
е	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
θ	0°	_	10°	0°	_	10°

# **SOLDERING FOOTPRINT\***

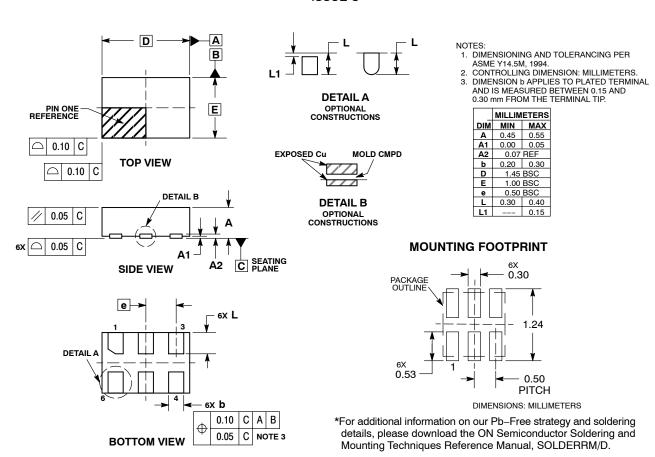


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLE 1: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. ANODE 6. CATHODE	STYLE 2: PIN 1. NO CONNECTION 2. COLLECTOR 3. EMITTER 4. NO CONNECTION 5. COLLECTOR 6. BASE	STYLE 3: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1	STYLE 4: PIN 1. COLLECTOR 2 2. EMITTER 1/EMITTER 2 3. COLLECTOR 1 4. EMITTER 3 5. BASE 1/BASE 2/COLLECTOR 3 6. BASE 3	STYLE 5: PIN 1. CHANNEL 1 2. ANODE 3. CHANNEL 2 4. CHANNEL 3 5. CATHODE 6. CHANNEL 4	STYLE 6: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE
STYLE 7: PIN 1. SOURCE 1 2. GATE 1 3. DRAIN 2 4. SOURCE 2 5. GATE 2 6. DRAIN 1	STYLE 8: PIN 1. EMITTER 1 2. BASE 2 3. COLLECTOR 2 4. EMITTER 2 5. BASE 1 6. COLLECTOR 1	STYLE 9: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 10: PIN 1. ANODE/CATHODE 2. BASE 3. EMITTER 4. COLLECTOR 5. ANODE 6. CATHODE	STYLE 11: PIN 1. EMITTER 2. BASE 3. ANODE/CATHOD 4. ANODE 5. CATHODE 6. COLLECTOR	DE

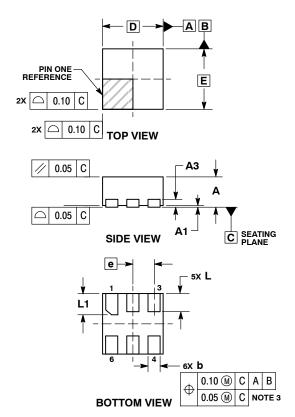
#### **PACKAGE DIMENSIONS**

# **UDFN6, 1.45x1.0, 0.5P**CASE 517AQ ISSUE O



#### PACKAGE DIMENSIONS

UDFN6, 1x1, 0.35P CASE 517BX ISSUE O

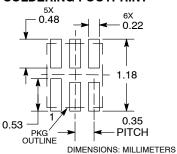


#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. DIMENSION 6 APPLIES TO PLATED
  TERMINAL AND IS MEASURED BETWEEN
  0.15 AND 0.20 MM EPOM TERMINAL TIP
- 0.15 AND 0.20 MM FROM TERMINAL TIP.
  4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS	
DIM	MIN	MAX
Α	0.45	0.55
A1	0.00	0.05
A3	0.13 REF	
b	0.12	0.22
D	1.00 BSC	
E	1.00 BSC	
е	0.35 BSC	
L	0.25	0.35
L1	0.30	0.40

# RECOMMENDED SOLDERING FOOTPRINT\*



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